NSN 5961-01-059-1713

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-059-1713 **Inclosure Material:** Glass **Overall Length:** 0.180 inches **Overall Diameter:** 0.075 inches **Mounting Method:** Terminal **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 20.000 microamperes forward current, average peak **Power Rating Per Characteristic:** 500.000 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0